

Digital Transistors (Built-in Resistors)

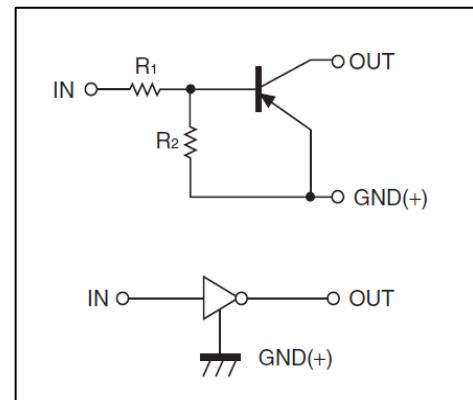
DTA113ZM/DTA113ZE/DTA113ZUA DTA113ZKA /DTA113ZCA/DTA113ZSA

DIGITAL TRANSISTOR (PNP)

FEATURES

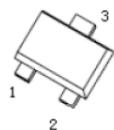
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy

• Equivalent Circuit



PIN CONNECTIONS and MARKING

DTA113ZM

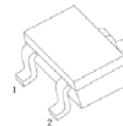


SOT-723

1. IN
2. GND
3. OUT

MARKING:E11

DTA113ZE

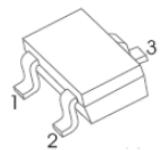


SOT-523

1. IN
2. GND
3. OUT

MARKING:E11

DTA113ZUA

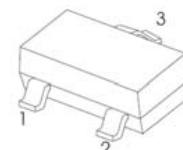


SOT-323

1. IN
2. GND
3. OUT

MARKING:E11

DTA113ZKA

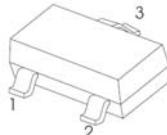


SOT-23-3L

1. IN
2. GND
3. OUT

MARKING:E11

DTA113ZCA



SOT-23

1. IN
2. GND
3. OUT

MARKING:E11

DTA113ZSA



TO-92S

1. GND
2. OUT
3. IN



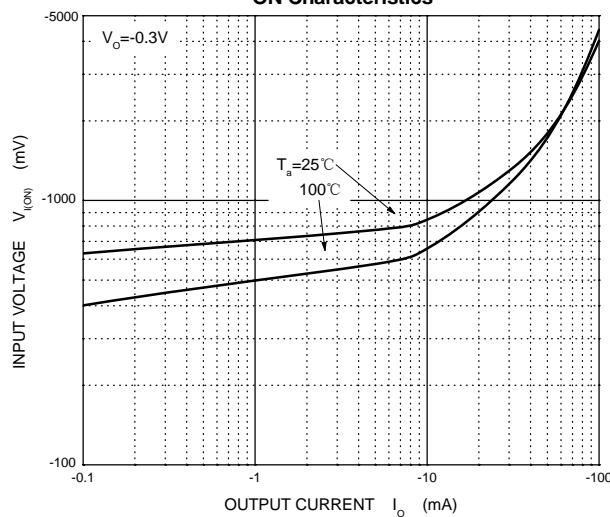
MAXIMUM RATINGS(Ta=25°C unless otherwise noted)

| Symbol | Parameter | Limits(DTA113Z□) | | | | | | Unit |
|------------------|----------------------|------------------|-----|-----|-----|-----|-----|------|
| | | M | E | UA | CA | KA | SA | |
| V _{CC} | Supply Voltage | -50 | | | | | | V |
| V _{IN} | Input Voltage | -10~+5 | | | | | | V |
| I _O | Output Current | -100 | | | | | | mA |
| P _D | Power Dissipation | 100 | 150 | 200 | 200 | 200 | 300 | mW |
| T _j | Junction Temperature | 150 | | | | | | °C |
| T _{stg} | Storage Temperature | -55~+150 | | | | | | °C |

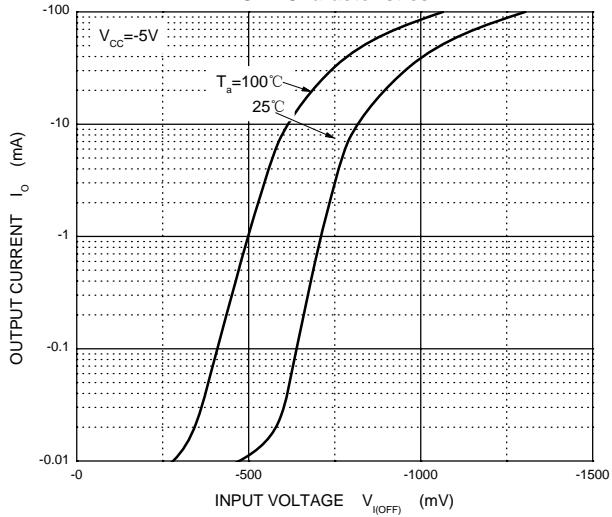
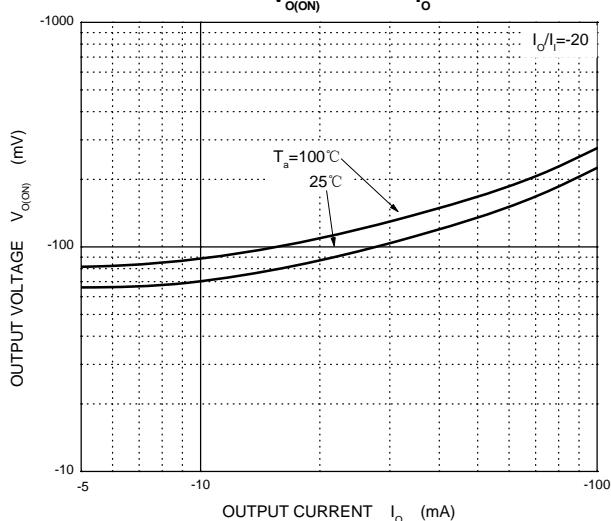
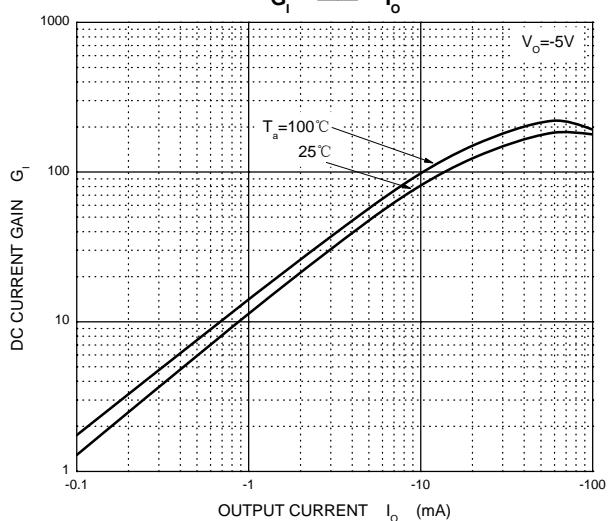
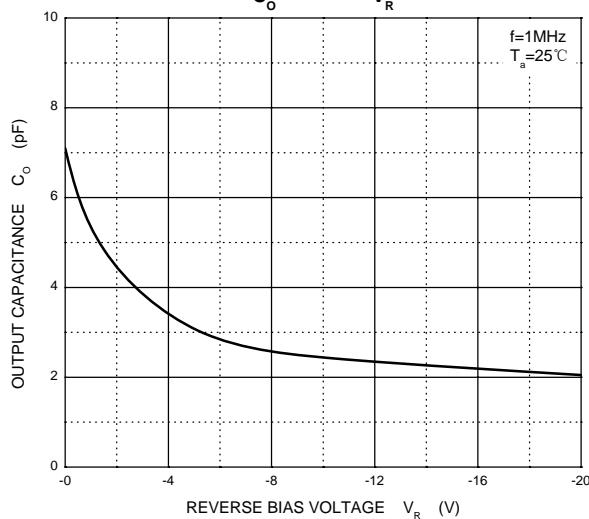
ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|----------------------|--------------------------------|--|------|-----|------|------|
| Input voltage | V _{I(off)} | V _{CC} =-5V,I _O =-100μA | -0.3 | | | V |
| | V _{I(on)} | V _O =-0.3V,I _O =-20mA | | | -3 | V |
| Output voltage | V _{O(on)} | I _O /I _I =-10mA/-0.5mA | | | -0.3 | V |
| Input current | I _I | V _I =-5V | | | -7.2 | mA |
| Output current | I _{O(off)} | V _{CC} =-50V,V _I =0 | | | -0.5 | μA |
| DC current gain | G _I | V _O =-5V,I _O =-5mA | 33 | | | |
| Input resistance | R ₁ | | 0.7 | 1 | 1.3 | kΩ |
| Resistance ratio | R ₂ /R ₁ | | 8 | 10 | 12 | |
| Transition frequency | f _T | V _O =-10V,I _O =-5mA,f=100MHz | | 250 | | MHz |

ON Characteristics



OFF Characteristics

 $V_{O(ON)} \text{ --- } I_o$  $G_i \text{ --- } I_o$  $C_o \text{ --- } V_R$  $P_D \text{ --- } T_a$ 